



# **MMDT5551**

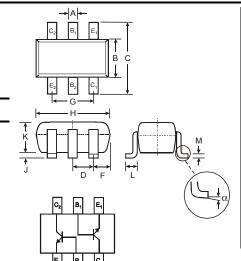
### **DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR**

### **Features**

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMDT5401)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device (Note 4 and 5)

### **Mechanical Data**

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: K4N, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)



|         | SOT-363  |        |  |  |  |  |  |  |  |  |  |
|---------|----------|--------|--|--|--|--|--|--|--|--|--|
| Dim     | Min      | Max    |  |  |  |  |  |  |  |  |  |
| Α       | 0.10     | 0.30   |  |  |  |  |  |  |  |  |  |
| В       | 1.15     | 1.35   |  |  |  |  |  |  |  |  |  |
| С       | 2.00     | 2.20   |  |  |  |  |  |  |  |  |  |
| D       | 0.65 N   | ominal |  |  |  |  |  |  |  |  |  |
| F       | 0.30     | 0.40   |  |  |  |  |  |  |  |  |  |
| Н       | 1.80     | 2.20   |  |  |  |  |  |  |  |  |  |
| J       | _        | 0.10   |  |  |  |  |  |  |  |  |  |
| K       | 0.90     | 1.00   |  |  |  |  |  |  |  |  |  |
| L       | 0.25     | 0.40   |  |  |  |  |  |  |  |  |  |
| М       | 0.10     | 0.25   |  |  |  |  |  |  |  |  |  |
| α       | 0°       | 8°     |  |  |  |  |  |  |  |  |  |
| All Din | nensions | in mm  |  |  |  |  |  |  |  |  |  |

## **Maximum Ratings** @TA = 25°C unless otherwise specified

| Characteristic                          |             | Symbol                            | Value       | Unit |
|---|-------------|-----------------------------------|-------------|------|
| Collector-Base Voltage                  |             | V <sub>CBO</sub>                  | 180         | V    |
| Collector-Emitter Voltage               |             | $V_{CEO}$                         | 160         | V    |
| Emitter-Base Voltage                    |             | $V_{EBO}$                         | 6.0         | V    |
| Collector Current - Continuous          | (Note 1)    | Ic                                | 200         | mA   |
| Power Dissipation                       | (Note 1, 2) | $P_d$                             | 200         | mW   |
| Thermal Resistance, Junction to Ambient | (Note 1)    | $R_{	hetaJA}$                     | 625         | °C/W |
| Operating and Storage Temperature Range |             | T <sub>j</sub> , T <sub>STG</sub> | -55 to +150 | °C   |

Notes:

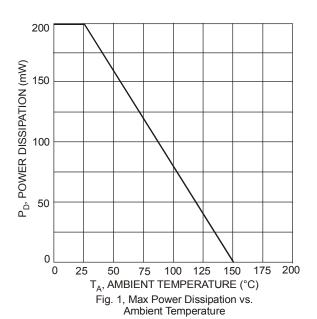
- 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. Maximum combined dissipation.
- 3. No purposefully added lead.
- 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
- 5. Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

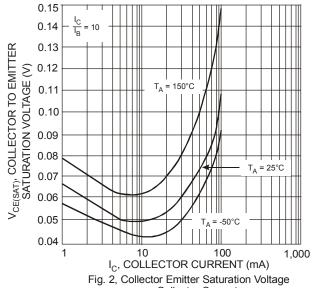


#### **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

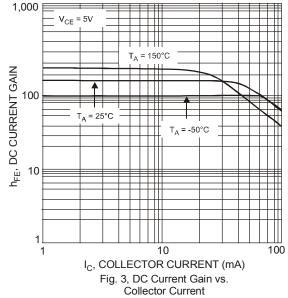
| Characteristic                       | Symbol               | Min            | Max          | Unit     | Test Condition   |
|--------------------------------------|----------------------|----------------|--------------|----------|--|
| OFF CHARACTERISTICS (Note 6)         | ·                    |                |              |          |  |
| Collector-Base Breakdown Voltage     | V <sub>(BR)CBO</sub> | 180            | _            | V        | $I_C = 100 \mu A, I_E = 0$   |
| Collector-Emitter Breakdown Voltage  | V <sub>(BR)CEO</sub> | 160            | _            | V        | $I_C = 1.0 \text{mA}, I_B = 0$   |
| Emitter-Base Breakdown Voltage       | V <sub>(BR)EBO</sub> | 6.0            | _            | V        | $I_E = 10 \mu A, I_C = 0$  |
| Collector Cutoff Current             | Ісво                 | _              | 50           | nA<br>μA | V <sub>CB</sub> = 120V, I <sub>E</sub> = 0<br>V <sub>CB</sub> = 120V, I <sub>E</sub> = 0, T <sub>A</sub> = 100°C |
| Emitter Cutoff Current               | I <sub>EBO</sub>     | _              | 50           | nA       | $V_{EB} = 4.0V, I_{C} = 0$   |
| ON CHARACTERISTICS (Note 6)          | ·                    |                |              |          |  |
| DC Current Gain                      | h <sub>FE</sub>      | 80<br>80<br>30 | 250<br>—     | _        | $I_C$ = 1.0mA, $V_{CE}$ = 5.0V<br>$I_C$ = 10mA, $V_{CE}$ = 5.0V<br>$I_C$ = 50mA, $V_{CE}$ = 5.0V                 |
| Collector-Emitter Saturation Voltage | V <sub>CE(SAT)</sub> | _              | 0.15<br>0.20 | V        | I <sub>C</sub> = 10mA, I <sub>B</sub> = 1.0mA<br>I <sub>C</sub> = 50mA, I <sub>B</sub> = 5.0mA                   |
| Base-Emitter Saturation Voltage      |                      | _              | 1.0          | V        | I <sub>C</sub> = 10mA, I <sub>B</sub> = 1.0mA<br>I <sub>C</sub> = 50mA, I <sub>B</sub> = 5.0mA                   |
| SMALL SIGNAL CHARACTERISTICS         | ·                    |                |              |          |  |
| Output Capacitance                   | $C_{obo}$            | _              | 6.0          | pF       | V <sub>CB</sub> = 10V, f = 1.0MHz, I <sub>E</sub> = 0  |
| Small Signal Current Gain            | h <sub>fe</sub>      | 50             | 250          |          | V <sub>CE</sub> = 10V, I <sub>C</sub> = 1.0mA, f = 1.0kHz  |
| Current Gain-Bandwidth Product       | f <sub>T</sub>       | 100            | 300          | MHz      | V <sub>CE</sub> = 10V, I <sub>C</sub> = 10mA, f = 100MHz   |
| Noise Figure                         | NF                   | _              | 8.0          | dB       | $V_{CE}$ = 5.0V, $I_{C}$ = 200 $\mu$ A, $R_{S}$ = 1.0k $\Omega$ , f = 1.0kHz                                     |

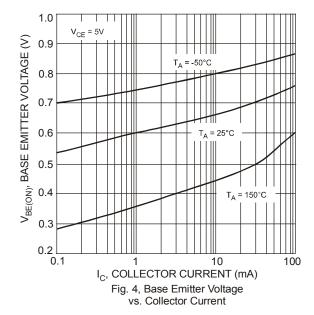
Notes: 6. Short duration pulse test used to minimize self-heating effect.

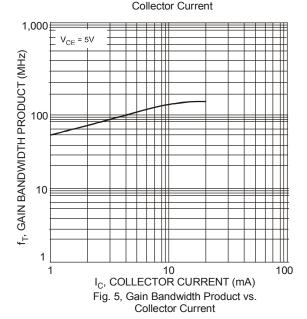










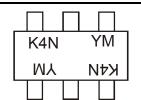


# Ordering Information (Note 7)

| ĺ | Device       | Packaging | Shipping         |  |  |
|---|--------------|-----------|------------------|--|--|
|   | MMDT5551-7-F | SOT-363   | 3000/Tape & Reel |  |  |

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

# **Marking Information**



K4N = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

| Date Code Ney |      |      |      |      |      |      |      |      |      |      |      |      |      |      |      |
|---------------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|------|
| Year          | 1998 | 1999 | 2000 | 2001 | 2002 | 2003 | 2004 | 2005 | 2006 | 2007 | 2008 | 2009 | 2010 | 2011 | 2012 |
| Code          | J    | K    | L    | М    | Ν    | Р    | R    | S    | Т    | U    | V    | W    | X    | Υ    | Z    |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code  | 1   | 2   | 3   | 4   | 5   | 6   | 7   | 8   | 9   | 0   | N   | D   |



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